

BUX85G

Switch-mode NPN Silicon Power Transistors

The BUX85G is designed for high voltage, high speed power switching applications like converters, inverters, switching regulators, motor control systems.

Features

- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO(sus)}$	450	Vdc
Collector-Emitter Voltage	V_{CES}	1000	Vdc
Emitter-Base Voltage	V_{EBO}	5	Vdc
Collector Current – Continuous	I_C	2	Adc
Collector Current – Peak (Note 1)	I_{CM}	3.0	Adc
Base Current – Continuous	I_B	0.75	Adc
Base Current – Peak (Note 1)	I_{BM}	1.0	Adc
Reverse Base Current – Peak	I_{BM}	1	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.4	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 5 Seconds	T_L	275	$^\circ\text{C}$

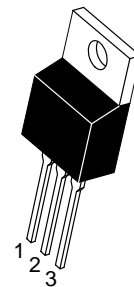
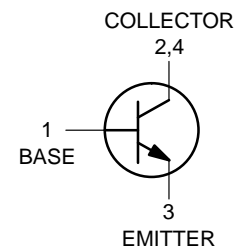
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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2.0 AMPERES POWER TRANSISTOR NPN SILICON 450 VOLTS, 50 WATTS



TO-220
CASE 221A
STYLE 1

MARKING DIAGRAM



BUX85 = Device Code
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
BUX85G	TO-220 (Pb-Free)	50 Units / Rail

BUX85G

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS (Note 2)

Collector–Emitter Sustaining Voltage (I _C = 100 mA _{dc} , L = 25 mH) See Figure 1	V _{CEO(sus)}	450	–	–	V _{dc}
Collector Cutoff Current (V _{CE} S = Rated Value) (V _{CE} S = Rated Value, T _C = 125°C)	I _{CES}	–	–	0.2 1.5	mA _{dc}
Emitter Cutoff Current (V _{EB} = 5 V _{dc} , I _C = 0)	I _{EBO}	–	–	1	mA _{dc}

ON CHARACTERISTICS (Note 2)

DC Current Gain (I _C = 0.1 A _{dc} , V _{CE} = 5 V)	h _{FE}	30	50	–	–
Collector–Emitter Saturation Voltage (I _C = 0.3 A _{dc} , I _B = 30 mA _{dc}) (I _C = 1 A _{dc} , I _B = 200 mA _{dc})	V _{CE(sat)}	–	–	0.8 1	V _{dc}
Base–Emitter Saturation Voltage (I _C = 1 A _{dc} , I _B = 0.2 A _{dc})	V _{BE(sat)}	–	–	1.1	V _{dc}

DYNAMIC CHARACTERISTICS

Current–Gain – Bandwidth Product (I _C = 500 mA _{dc} , V _{CE} = 1.0 V _{dc} , f = 1 MHz)	f _T	4	–	–	MHz
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SWITCHING CHARACTERISTICS

Turn–on Time	V _{CC} = 250 V _{dc} , I _C = 1 A I _{B1} = 0.2 A, I _{B2} = 0.4 A See Figure 2	t _{on}	–	0.3	0.5	μs
Storage Time		t _s	–	2	3.5	μs
Fall Time		t _f	–	0.3	–	μs
Fall Time		Same above cond. at T _C = 95°C	t _f	–	–	1.4

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: PW = 300 μs, Duty Cycle ≤2%.

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TYPICAL CHARACTERISTICS

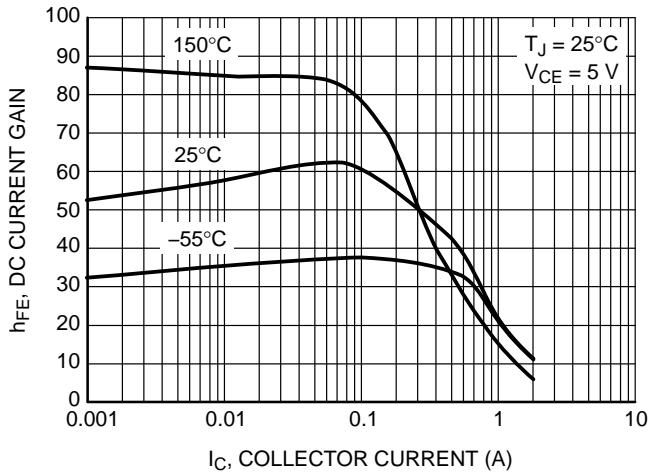


Figure 1. DC Current Gain

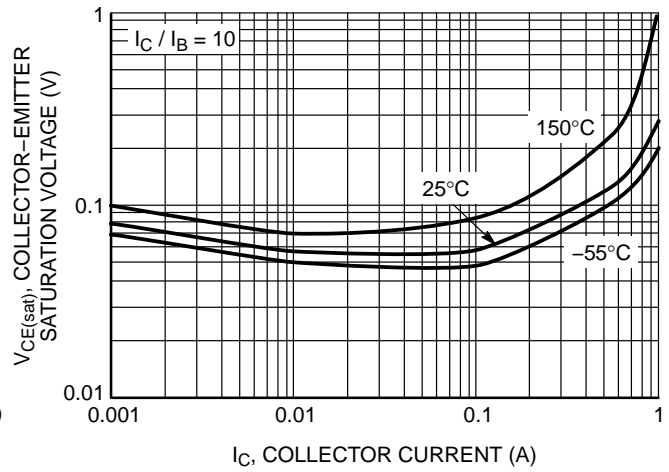


Figure 2. $V_{CE(sat)}$, Collector Emitter Saturation Voltage

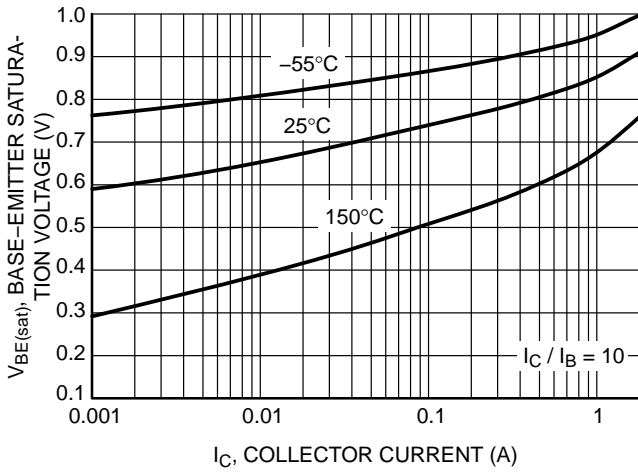


Figure 3. $V_{BE(sat)}$, Base Emitter Saturation Voltage

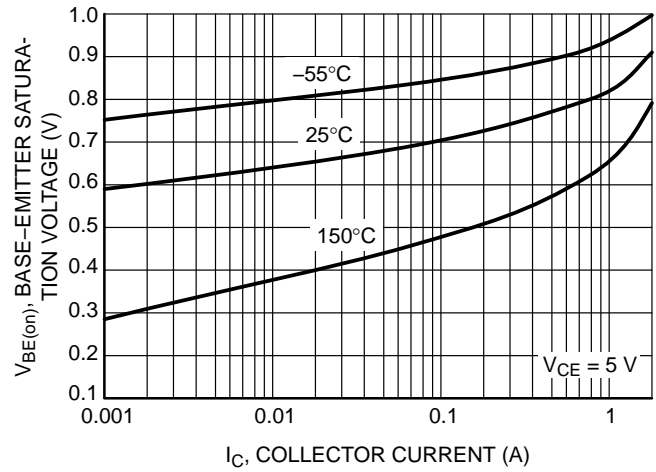


Figure 4. $V_{BE(on)}$, Base Emitter On Voltage

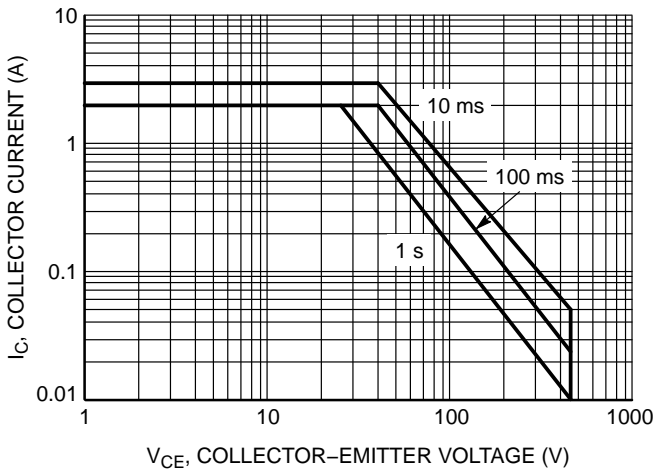


Figure 5. Safe Operating Area (SOA)

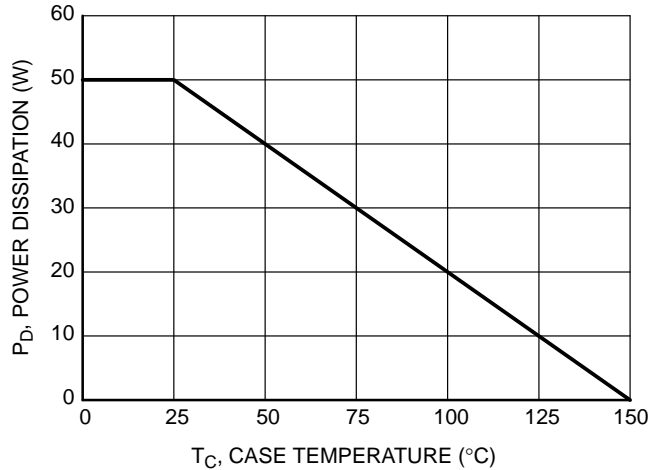


Figure 6. Power Derating

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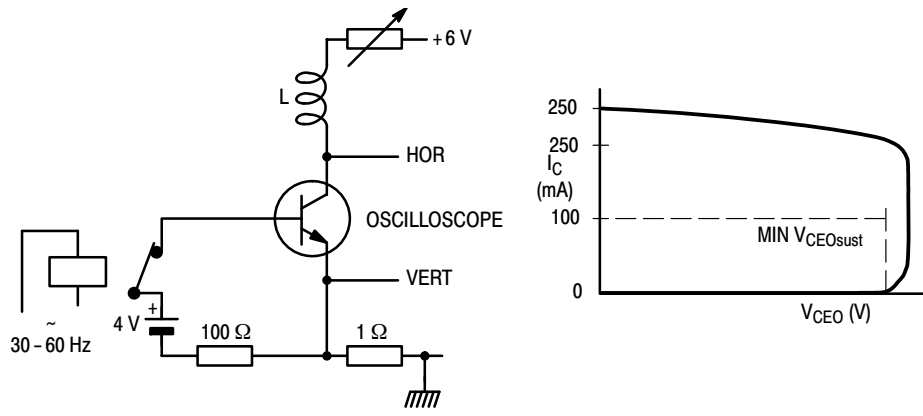


Figure 1. Test Circuit for $V_{CEOsust}$

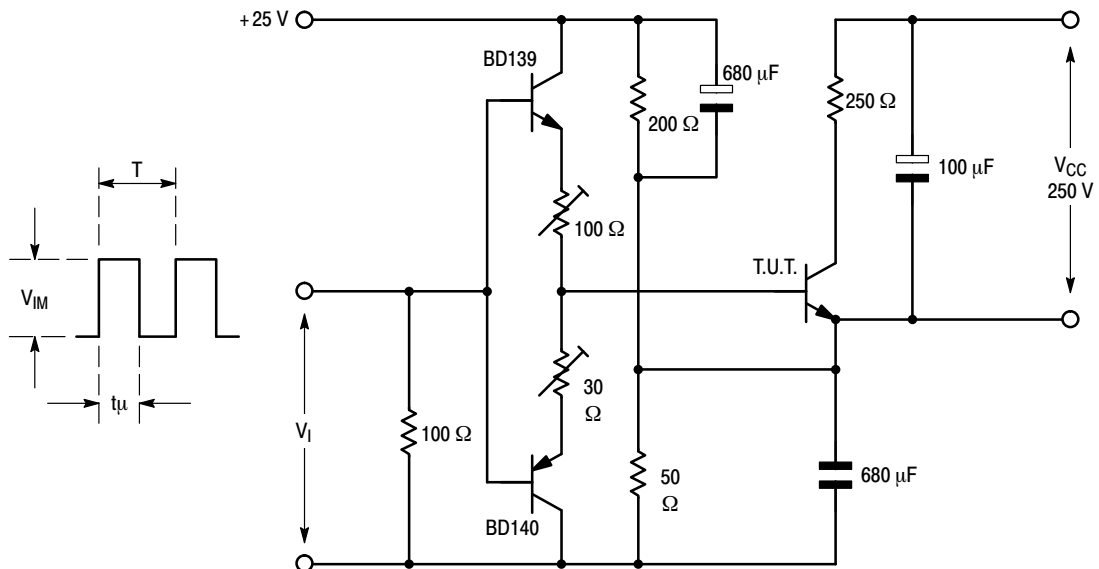
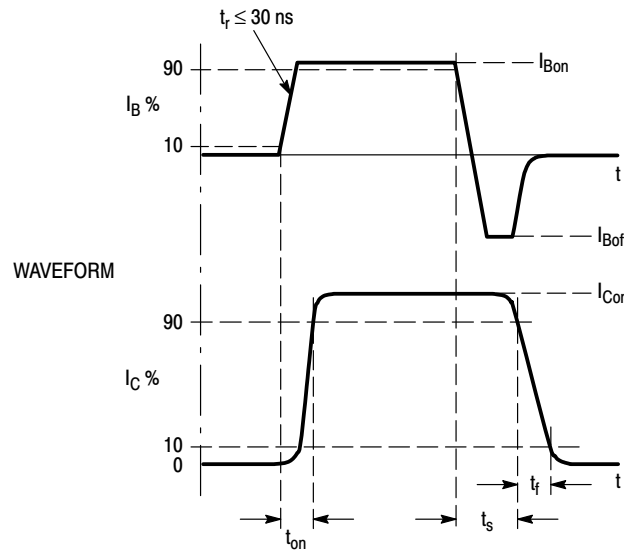


Figure 2. Switching Times/Test Circuit

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